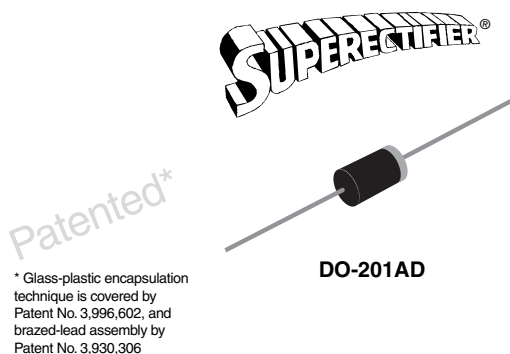


Glass Passivated Junction Rectifier



FEATURES

- Superrectifier structure for high reliability application
- Cavity-free glass-passivated junction
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- Meets environmental standard MIL-S-19500
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in general purpose rectification of power supplies, inverters, converters and freewheeling diodes application.

MECHANICAL DATA

Case: DO-201AD, molded epoxy over glass body

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	3.0 A
V_{RRM}	200 V to 800 V
I_{FSM}	125 A
I_R	5.0 μ A
V_F	0.95 V
T_J max.	175 °C

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted) ⁽¹⁾						
PARAMETER	SYMBOL	1N5624GP	1N5625GP	1N5626GP	1N5627GP	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	200	400	600	800	V
Maximum DC blocking voltage	V_{DC}	200	400	600	800	V
Maximum average forward rectified current 0.375" (9.5 mm) lead length at $T_A = 70$ °C	$I_{F(AV)}$	3.0				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	125				A
Maximum full load reverse current, full cycle average 0.375" (9.5 mm) lead length at $T_A = 70$ °C	$I_{R(AV)}$	200				μ A
Operating junction and storage temperature range	T_J, T_{STG}	- 65 to + 175				°C

Note:

(1) JEDEC registered values

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	1N5624GP	1N5625GP	1N5626GP	1N5627GP	UNIT
Maximum instantaneous forward voltage ^(1,2)	3.0 A	T _A = 25 °C T _A = 70 °C	V _F	1.0 0.95				V
Maximum DC reverse current at rated DC blocking voltage		T _A = 25 °C	I _R	5.0				μA
		T _A = 150 °C		300		200		
Typical reverse recovery time	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}	3.0				μs
Typical junction capacitance	4.0 V, 1 MHz		C _J	40				pF

Notes:

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
(2) JEDEC registered values

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)						
PARAMETER	SYMBOL	1N5624GP	1N5625GP	1N5626GP	1N5627GP	UNIT
Typical thermal resistance ⁽¹⁾	$R_{\theta JA}$	20				$^{\circ}\text{C/W}$

Note:

- (1) Thermal resistance from junction to ambient, and from junction to lead at 0.375" (9.5 mm) lead length, P.C.B. mounted

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
1N5626GP-E3/54	1.28	54	1400	13" diameter paper tape and reel
1N5626GP-E3/73	1.28	73	1000	Ammo pack packaging
1N5626GPHE3/54 ⁽¹⁾	1.28	54	1400	13" diameter paper tape and reel
1N5626GPHE3/73 ⁽¹⁾	1.28	73	1000	Ammo pack packaging

Note:

- (1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

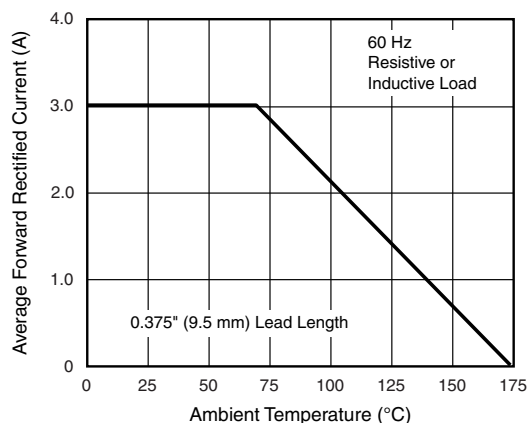


Figure 1. Forward Current Derating Curve

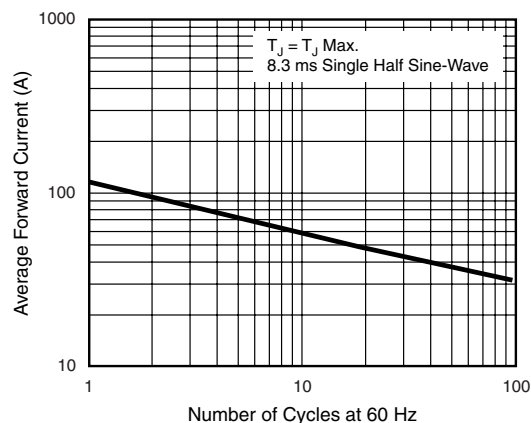


Figure 2. Maximum Non-repetitive Peak Forward Surge Current

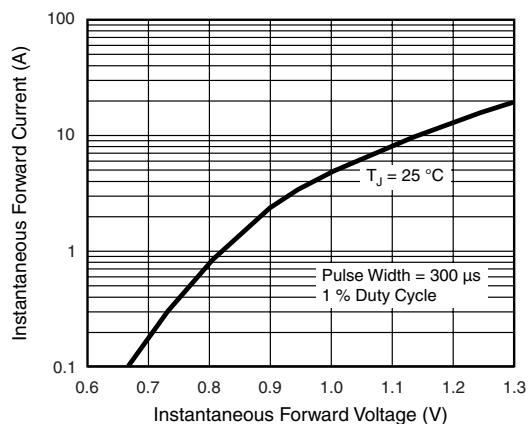


Figure 3. Typical Instantaneous Forward Characteristics

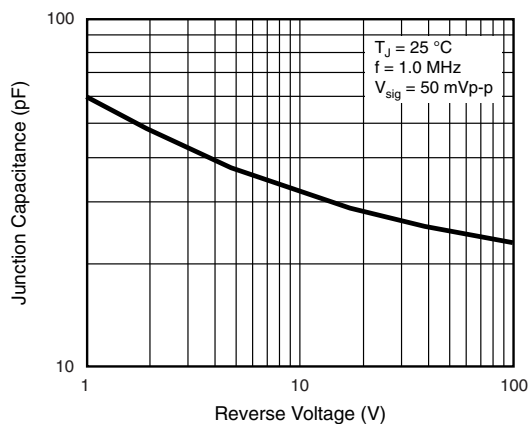


Figure 5. Typical Junction Capacitance

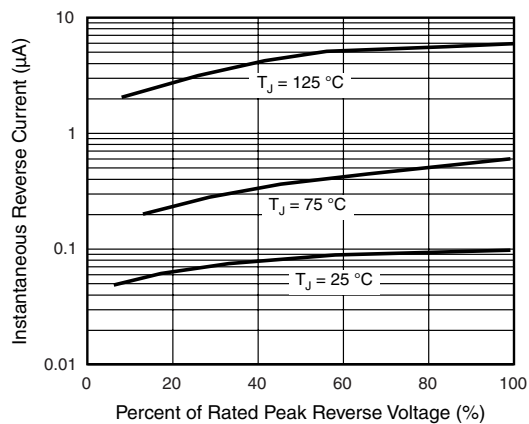


Figure 4. Typical Reverse Characteristics

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

